

Ground-state properties and molecular theory of Curie temperature in the coherent potential approximation of diluted magnetic semiconductors

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Using spin- $\frac{1}{2}$ description of valence holes and Kondo coupling between local spins and carriers, GaAs-based III-V diluted magnetic semiconductors (DMS) are studied in the coherent potential approximation (CPA). Our calculated relation of ground-state energy and impurity magnetization shows that ferromagnetism is always favorable at low temperatures. For very weak Kondo coupling, the density of states (DOS) of the host semiconductor is not modified much. Impurity band can be generated at the host band bottom only when Kondo coupling is strong enough. Using Weiss molecular theory, we predict a linear relation of Curie temperature with respect to Kondo coupling and doping concentration x if the hole density is proportional to x .

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The ferromagnetism of DMS of III-V-type is not well understood. To explain ferromagnetism in DMS, various models and approaches have been proposed[1]-[6]. Though the models differ from each other in details, they all agree that the coupling between the carriers and local spins is of fundamental importance. An issue of debate, however, is how the exchange between localized spins is induced by the carriers. One model for this induced exchange is the Ruderman-Kittel-Kasuya-Yosida (RKKY) interaction[1][2]. Another version which results in conclusion equivalent to RKKY is the Zener model[4] which uses the fact that the valence holes are on p -orbitals. A third model is the double-exchange (DE) mechanism[7]. But this model is inconsistent with the charge-transfer properties[4]. Though RKKY can give a Curie temperature in agreement with experiment, some argue that the RKKY model breaks down here[5][8] because the local coupling between the carrier and the impurity spin is much larger than the Fermi energy and can not be treated perturbatively. In dealing with the effect of the localized spins, a key issue is whether or not randomness should be taken into consideration. The above models are all mean field approximations (MFA) which assume homogeneity and neglect randomness. But DMSs are disordered systems with positional disorder of Mn impurities. As concluded in[2][9], disorder has a substantial influence upon carrier magnetic susceptibility. Hence, any first principle consideration should take into account the randomness of the impurities.

A classic method of dealing with randomness is the coherent potential approximation (CPA)[10] which has been applied to DMS[11]-[13]. Basing on the formalism of[14] and assuming very large local spin S while keeping the product IS constant (where I is the Kondo-like interaction), [11] obtained the density of states and the relation between Curie temperature and the doping concentration. Using the averaged carrier Green's function, Bouzerar et al[13] arrived at the conclusion that the lo-

cal coupling between the carrier and the impurity spins must be intermediate in order to acquire ferromagnetism. In this paper, we use the formalism of CPA in [15] to study the ground-state properties of III-V DMS. In contrast to [12], we keep $S = 5/2$ and treat the impurity spins fully quantum mechanically. Though it is mostly accepted that the effective spin of valence holes is $\frac{3}{2}$ [16]-[20], we describe here the holes as spin- $\frac{1}{2}$ fermions. It is usually believed that such a description can still catch the essential physics. Because of spin-orbit interaction, the p -orbitals are split (with split-off $\simeq 0.34\text{eV}$) into a spin-3/2 multiplet and a spin-1/2 multiplet[21]. Using spherical approximation, the kinetic energy of the Luttinger-Kohn Hamiltonian [21] for the spin-3/2 multiplet takes the form $\sum_{\mu} (\hbar^2 \mathbf{k}^2 / 2m_{\mu}) c_{\mathbf{k}\mu}^{\dagger} c_{\mathbf{k}\mu}$ near the valence top after diagonalization, where $m_{\mu} = m_h \simeq 0.5m$ for $\mu = \pm 3/2$ and $m_{\mu} = m_{\ell} \simeq 0.07m$ for $\mu = \pm 1/2$ (m is the effective mass of a free hole). The interaction between the spin of holes and local 5/2-spins now takes a $\mathbf{k}$ -dependent form $\sum_{\mathbf{k}, \mathbf{k}'} \mathbf{S} \cdot c_{\mathbf{k}}^{\dagger} \mathbf{J}(\mathbf{k}, \mathbf{k}') c_{\mathbf{k}'} \exp(-i(\mathbf{k} - \mathbf{k}') \cdot \mathbf{R})$ [18]. Since the DOS for parabolic band is $g(\varepsilon) = (1/2\pi^2 \hbar^3) (2m)^{3/2} \sqrt{\varepsilon}$, we have the ratio of DOS $g_h(\varepsilon)/g_{\ell}(\varepsilon) \simeq 19$ for heavy holes and light holes, i.e., about 95% of valence holes are heavy holes. Therefore, it is a valid approximation to consider only heavy holes. What is more, since the hole density is very small, the Fermi wave vector is supposed to be very small and it is thus a good reasonable approximation to consider those $\mathbf{k}$ values in the interaction term. And this leads to the usual assumption that the carriers are shallow holes and the coupling of the shallow holes to the Mn^{2+} can be described by local Kondo interaction between 5/2-spins and 1/2-spins.

We study here one of the most commonly studied DMS $\text{Ga}_{1-x}\text{Mn}_x\text{As}$, where the doping concentration x varies from 0.015 to 0.075 in region of interest for ferromagnetism[1]. In $\text{Ga}_{1-x}\text{Mn}_x\text{As}$, ferromagnetism was first realized at Curie temperature of 110K[2]. The carriers are holes originating from randomly distributed

Mn. The system is highly compensated[22]-[24] with a hole density p only around 10% of the Mn density x . There are different kinds of randomness, e.g. substitutional randomness, interstitial randomness, antisite randomness, and directional randomness of impurity spin. It is commonly agreed now that interstitial Mn atoms and antisite As only reduce the hole densities and do not affect conduction of holes significantly. Therefore we consider only two kinds of randomness, i.e., the random substitution of the Mn atoms and the random direction of the impurity spins. The model Hamiltonian in our description is

$$H = \sum_{\mathbf{i}, \mathbf{j}, \sigma} t_{\mathbf{ij}} c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{j}\sigma} + \sum_{\mathbf{i}} u_{\mathbf{i}} \quad (1)$$

where $u_{\mathbf{i}}$ depends on whether $\mathbf{i}$ is a Ga or Mn site. For Ga-site $u_{\mathbf{i}} = u_{\mathbf{i}}^G = E_G \sum_{\sigma} c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{i}\sigma}$, and for Mn-site $u_{\mathbf{i}} = u_{\mathbf{i}}^M = E_M \sum_{\sigma} c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{i}\sigma} + J_K \mathbf{S}_{\mathbf{i}} \cdot \mathbf{s}_{\mathbf{i}}$. $\mathbf{S}_{\mathbf{i}}$ is the local spin of Mn at site $\mathbf{i}$, $\mathbf{s} = (1/2)c_{\sigma}^\dagger \boldsymbol{\tau}_{\sigma\sigma'} c_{\sigma'}$ is the spin of a hole where $c_{\sigma}^\dagger (c_{\sigma})$ is the creation(annihilation) operators for holes, spin indices $\sigma, \sigma' = \uparrow, \downarrow$, and $\boldsymbol{\tau} = (\tau_1, \tau_2, \tau_3)$ are the three usual Pauli matrices. E_M and E_G are the on-site energies for Ga and Mn and are assumed constant. The hopping energy $t_{\mathbf{ij}} = t$ if $\mathbf{i}, \mathbf{j}$ are nearest neighbors and zero otherwise and $J_K > 0$ is the local Kondo coupling. The details of the lattice structure are not crucial in the following discussion. According to the general scheme of CPA, the virtual unperturbed Hamiltonian is

$$\mathcal{H}(\varepsilon) = \sum_{\sigma, \mathbf{k}} (t_{\mathbf{k}} + \Sigma_{\sigma}(\varepsilon)) c_{\mathbf{k}\sigma}^\dagger c_{\mathbf{k}\sigma} \quad (2)$$

where ε is the Fourier frequency variable, $\Sigma_{\sigma}(\varepsilon)$ is the CPA self-energy to be determined self-consistently and $t_{\mathbf{k}}$ is the Fourier transformation of $t_{\mathbf{ij}}$. Then the relative perturbation V is given by

$$V = H - \mathcal{H}(\varepsilon) = \sum_{\mathbf{i}} v_{\mathbf{i}} \quad (3)$$

where $v_{\mathbf{i}} = v_{\mathbf{i}}^G = \sum_{\sigma} (E_G - \Sigma_{\sigma}) c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{i}\sigma}$ for Ga and $v_{\mathbf{i}} = v_{\mathbf{i}}^M = \sum_{\sigma} (E_M - \Sigma_{\sigma}) c_{\mathbf{i}\sigma}^\dagger c_{\mathbf{i}\sigma} + J_K \mathbf{S}_{\mathbf{i}} \cdot \mathbf{s}_{\mathbf{i}}$ for Mn. The reference Green's function is $\langle \mathbf{i}\sigma | \mathcal{R}(\varepsilon) | \mathbf{j}\sigma' \rangle = \langle 0 | c_{\mathbf{i}\sigma} (\varepsilon - \mathcal{H})^{-1} c_{\mathbf{j}\sigma'}^\dagger | 0 \rangle$ where $|0\rangle$ is the vacuum state of the c -operators, and the associated t -matrices are $t_{\mathbf{i}}^G = v_{\mathbf{i}}^G / (1 - \mathcal{R}v_{\mathbf{i}}^G)$, $t_{\mathbf{i}}^M = v_{\mathbf{i}}^M / (1 - \mathcal{R}v_{\mathbf{i}}^M)$. So the CPA equation and DOS are given by

$$(1-x)t_{\mathbf{i}}^G + x\langle t_{\mathbf{i}}^M \rangle_{\text{spin}} = 0 \quad (4)$$

and

$$g_{\sigma}(\varepsilon) = -\frac{1}{\pi} \text{Im} F_{\sigma}(\varepsilon) \quad (5)$$

where $\langle \dots \rangle_{\text{spin}}$ denotes average over the configurations of impurity spins and $F_{\sigma}(\varepsilon) = \langle \sigma | \mathcal{R} | \sigma \rangle = (1/N) \sum_{\mathbf{k}} [1/(\varepsilon - t_{\mathbf{k}} - \Sigma_{\sigma})]$, where N is the number of lattice sites. As usual, the spin-resolved bare DOS (for undoped GaAs) can be approximated by the semicircle DOS

$$g_0(\varepsilon) = \frac{2}{\pi \Delta} \sqrt{1 - \left(\frac{\varepsilon}{\Delta}\right)^2} \quad (6)$$

where Δ denotes the half-band width. At zero temperature, the carrier density for spin σ can be expressed as $n_{\sigma} = \int_{-\infty}^{\varepsilon_F} g_{\sigma}(\varepsilon) d\varepsilon$, where ε_F is the Fermi energy, and the total carrier density $n = n_{\uparrow} + n_{\downarrow}$. The total electronic ground-state energy per site is $\varepsilon_g = \int_{-\infty}^{\varepsilon_F} \varepsilon [g_{\uparrow}(\varepsilon) + g_{\downarrow}(\varepsilon)] d\varepsilon$. Defining $V_{\uparrow} = E_M - \Sigma_{\uparrow} + (J_K/2)S^z$, $V_{\downarrow} = E_M - \Sigma_{\downarrow} - (J_K/2)S^z$, $U_{\sigma} = V_{\sigma} - J_K/2$, $W_{\uparrow} = (1/4)J_K^2 S^- S^+$, $W_{\downarrow} = (1/4)J_K^2 S^+ S^-$, the CPA equations can be written as

$$(1-x) \frac{E_G - \Sigma_{\uparrow}}{1 - F_{\uparrow}(E_G - \Sigma_{\uparrow})} + x \langle [V_{\uparrow}(1 - F_{\downarrow}U_{\downarrow}) + F_{\downarrow}W_{\uparrow}] \frac{1}{(1 - F_{\uparrow}V_{\uparrow})(1 - F_{\downarrow}U_{\downarrow}) - F_{\uparrow}F_{\downarrow}W_{\uparrow}} \rangle_{\text{spin}} = 0 \quad (7)$$

$$(1-x) \frac{E_G - \Sigma_{\downarrow}}{1 - F_{\downarrow}(E_G - \Sigma_{\downarrow})} + x \langle [V_{\downarrow}(1 - F_{\uparrow}U_{\uparrow}) + F_{\uparrow}W_{\downarrow}] \frac{1}{(1 - F_{\downarrow}V_{\downarrow})(1 - F_{\uparrow}U_{\uparrow}) - F_{\downarrow}F_{\uparrow}W_{\downarrow}} \rangle_{\text{spin}} = 0 \quad (8)$$

These relations are given in [15] in another context. For any $f(S^z)$, the spin average is given by $\langle f(S^z) \rangle_{\text{spin}} = \sum_{S^z=-S}^S e^{\lambda S^z} f(S^z) / \sum_{S^z=-S}^S e^{\lambda S^z}$ where λ is determined by the condition $\langle S^z \rangle_{\text{spin}} = m$, m is the given magnetization of the impurity spins. In our single-particle

CPA, the Callen-Shtrikman relation[25] that tells there is a one-to-one correspondence between m and $\langle (S^z)^n \rangle_{\text{spin}}$ for $n > 1$ applies. Corresponding to bare DOS, we have $F^{(0)}(\varepsilon) = (2/\Delta^2)(\varepsilon - \sqrt{\varepsilon^2 - \Delta^2})$ so $F_{\sigma}(\varepsilon) = F^{(0)}(\varepsilon - \Sigma_{\sigma})$. Solving for Σ_{σ} , we have $\Sigma_{\sigma} = \varepsilon - (\Delta^2/4)F_{\sigma} - 1/F_{\sigma}$.

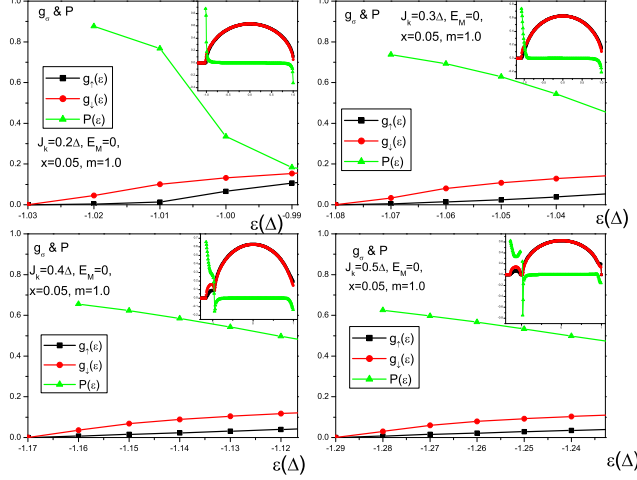


FIG. 1: DOS and polarization for a number of model parameters

Therefore CPA equations can be turned into equations for functions F_σ for a given ε . Once $F_\sigma(\varepsilon)$ are known, DOS $g_\sigma(\varepsilon)$ and quantities like Fermi energy can be calculated.

To solve CPA equations (7) and (8), we chose $x = 0.05, p = 0.1x$ and set $E_G = 0$ since we can shift the chemical potential without loss of physics. Energies are normalized so that $\Delta = 1$. The solution of $F_\sigma(\varepsilon)$ is generated by iteration starting from $F^{(0)}$. First, we use the small value of x to generate Σ_σ and then use the resulting Σ_σ to generate F_σ . We calculated the DOS and the spin polarization $P(\varepsilon)$ [26] for model parameters $J_K = 0.1, 0.2, 0.3, 0.4, 0.5, 0.6, E_M = 0, -0.2, -0.4, -0.6$ with $m = 0.05, 1.0, 1.5, 2.0, 2.5$. As a check for our numerical results, the sum rule $\int_{-\infty}^{\infty} g_\sigma(z) dz = 1$ is preserved and the relation $n_\uparrow + n_\downarrow = p$ is also preserved where n_σ is calculated from spin-resolved DOS respectively. In FIG.1 we show some of our results. The curves presented in the main panels of FIG.1 are from the bottom of the band to Fermi energies at zero temperature for clarity since this portion is important for low temperature physics. The insets outline the full behavior. It is seen that for very weak Kondo couplings such as $J_K = 0.2\Delta, 0.3\Delta$, there are no impurity bands and the DOS is not substantially different from the bare DOS in shape. Only when Kondo coupling becomes strong enough can there be impurity bands and corresponding peaks. In contrast to the conclusion of classical spin approximation[12], the spin polarizations are not constant up to Fermi energies. Fig.1 shows that for $m > 0$, there are always more spin-down carriers than spin-up carriers, in compliance with the fact that the local p - d coupling is antiferromagnetic[4]. Another substantial

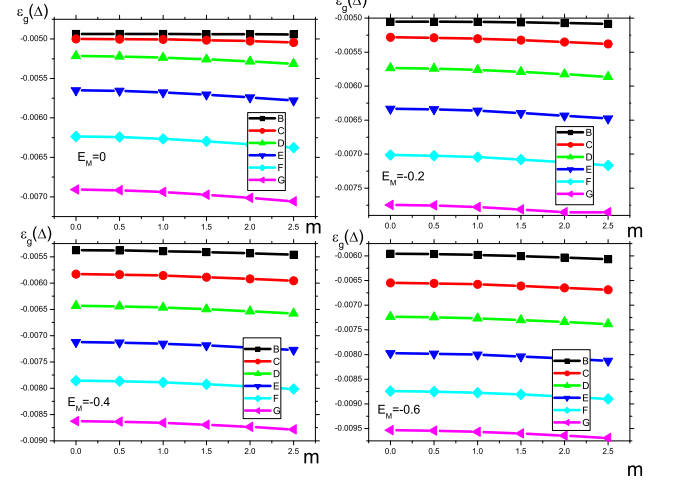


FIG. 2: Relation of ε_g versus m . B: $J_K = 0.1$; C: $J_K = 0.2$; D: $J_K = 0.3$; E: $J_K = 0.4$; F: $J_K = 0.5$; G: $J_K = 0.6$

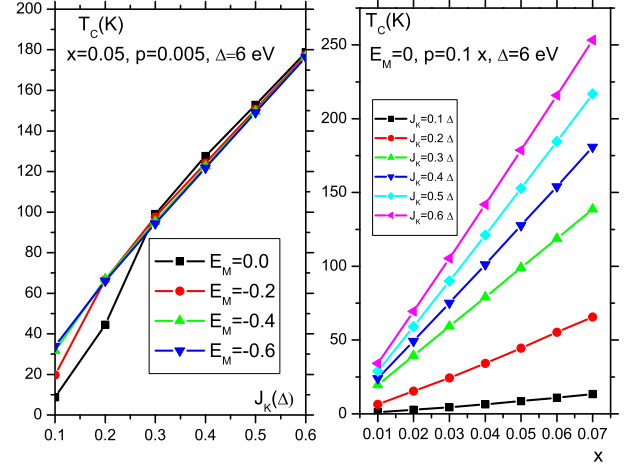


FIG. 3: Theoretical estimation of Curie temperature using Weiss molecular theory

difference between our calculated DOS and that in[12] is that there is no impurity peak above the top of the band in our calculation. So the $\varepsilon \leftrightarrow -\varepsilon$ symmetry of the bare DOS is broken by the impurities.

FIG.2 shows the relation between ground-state energy per site and the impurity magnetization m . In actual calculation of ground-state energy, an important issue is the determination of the Fermi energy which is fixed by the integration of an interpolation function of the DOS. If the interval $\delta\varepsilon$ is not small enough, the integral of the interpolated DOS may vary significantly with the choice

of $\delta\varepsilon$. To make it stable enough, we choose $\delta\varepsilon = 5 \times 10^{-4}$ to interpolate DOS linearly. Our results show that for all the chosen values of model parameters, the ground-state energy per site always decreases, though very slowly, with increase of impurity magnetization. Therefore CPA predicts that at very low temperatures, ferromagnetism is always energetically favorable for all the model parameters considered.

In FIG.3, we show the dependence of Curie temperature on the model parameters and the doping concentration. Weiss molecular field theory is employed as follows to calculate the Curie temperature. Given m , one can calculate DOS and then $\langle s_z \rangle$. So one can establish relation $\langle s_z \rangle = \langle s_z \rangle(m)$. On the other hand, given $\langle s_z \rangle$, each impurity spin feels an effective field $J_K \langle s_z \rangle$ and thus we have $m = SB_S(\beta h)$ with $h = -J_K \langle s_z \rangle(m)$, $\beta = 1/k_B T$ and $B_S(x)$ the conventional Brillouin function. For very small m , we have $\langle s_z \rangle \simeq -Am$ with $A > 0$ and we have $\beta h \simeq \beta J_K A m$. So $B_S(\beta h) \simeq (S+1)\beta h/3$ and thus the Curie temperature can be estimated by $k_B T_C \simeq J_K S(S+1)A/3$. For small m , letting $F_\uparrow(z) = F(z) + \psi(z)m$, $F_\downarrow(z) = F(z) - \psi(z)m$ where $F(z)$ is the paramagnetic solution, we have

$$A(J_K, E_M, x, \beta) \simeq \frac{1}{\pi} \int_{-\infty}^{\varepsilon_F} d\varepsilon \text{Im} \psi(\varepsilon) \quad (9)$$

where we have ignored the β -dependence. As our numerical results (not shown here) indicate, the chemical potential is very close to the zero temperature Fermi energy in a wide range of temperatures ($\beta > 100$), showing that the Fermi function can be approximated by the zero temperature step function. Since the width of full valence band of GaAs is about 10–12 eV (the width of Γ_8 band ~ 4 eV)[27], here we take $\Delta = 6$ eV. The left panel in FIG.3 shows the relation of T_C versus J_K for different values of E_M . The curves exhibit a linear relation. For $J_K > 0.3$, T_C is almost independent of E_M . The right panel shows the dependence of Curie temperature on the doping concentration for $E_M = 0$ and various values of J_K . Here we still assume that the hole density $p = 0.1x$. Again, the relation indicated is linear in the range $0.01 < x < 0.07$. Fig.3 suggests that to reach the observed $T_C = 110$ K, the value of J_K needs to be $0.3\Delta - 0.4\Delta$. For $\Delta = 6$ eV, this value is much larger than the value 1 eV calculated in [17]. But it is still within the possible range proposed in [28]. Like in the dynamical mean field study[29] which also used semicircle density of states and bandwidth ~ 10 eV, the crucial issue in our current CPA study is the behaviors of the Curie temperature versus the model parameters. The resulting numbers of Curie temperatures can be scaled up or down depending on the choice of the bandwidth.

To conclude, we summarize our results here. Using CPA and treating the impurity spins fully quantum mechanically, we have calculated the ground-state energies of GaAs-based III-V DMS for a wide range of model pa-

rameters. The results show that ferromagnetism is always preferable at low temperatures. Unlike the classical treatment of the impurity spins, our approach predicts that impurity band can arise only at bottom of the band of the host system, showing asymmetry caused by doping. With the help of Weiss molecular theory of ferromagnetism, we obtained a linear relation of Curie temperature with respect to Kondo coupling and doping concentration. Our results agrees with that in[30]. As is known from experiments [1][22], T_C increases almost linearly with x for $x < 0.053$ and starts to drop when x becomes larger. The contradiction might be reconciled by the dependence on x of the exchange integral (usually denoted as $N_0\beta$). It is found in [28] that the absolute value $N_0\beta$ decreases as x increases, a behavior already well known to occur in $\text{Co}_{1-x}\text{Mn}_x\text{S}$. Therefore, if there is a relation like $J_K = -ax + b$ with a and $b > 0$, as suggested by the data given in [28], it can be expected that the resulting Curie temperature may start to decrease at certain point of doping concentration.

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